

MAINTENANCE MANUAL 851-870 MHz, 35 WATT POWER AMPLIFIER ASSEMBLY 19D430488G1, 2

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DESCRIPTION

The power amplifier assembly for MASTR® II uses six RF power transistors to provide a maximum of 35 Watts output power, R24 located on the PA module, is used to adjust the output power to any level from 7 Watts to rated RF power output. The power control circuit consists of R24, Q207, Power Control IC (U1), and a directional coupler.

SUPPLY VOLTAGE AND METERING

Supply voltage is connected through power leads from the system board to feed-through capacitor C219. C219 prevents RF from getting on the power leads.

Centralized metering jack J205 is provided for use with GE Test Model 4EX3All or Test Kit 4EX8Kl2. The test set meters the AMPL-1 DRIVE (exciter output), the POWER CONTROL voltage, and the DRIVER AND PA CURRENT.

CIRCUIT ANALYSIS

PA ASSEMBLY

The exciter output is coupled through a 50 ohm RF cable to the PA input connector P101. The RF input is coupled through a matching network composed of C2, C3, L1, L2 and L3 to the base of power amplifier Q201.

Part of the RF input is rectified by CR1 and metered at J205-4 through resistor R21. The rectified RF is also applied to the power control IC (U1).

Collector voltage to Q201 is applied from the power controller through collector stabilizing network L5 and R4 and collector feed network L4 and C201.

The output of Q201 is coupled to the base of the second power amplifier Q202 $\,$

through coupling capacitor C5, and a matching network consisting of C6, C7 L6 and L7.

Collector voltage to Q202 is controlled by power control IC (U1), and Q207 and is applied through a collector stabilizing network L11 and R7 and collector feed network C202 and L10.

The output of Q202 is coupled to the base of power amplifier Q203 through C9 and the matching network of C203, C204, C10, L13, L14 and L15.

The collector voltage to Q203 is coupled directly from the supply voltage through collector stabilizing network L17 and R9 and collector feed network L16 and C11.

The output of Q203 is coupled through an impedance matching network (C206, C13, C207, C208, L18, L19, L20 and L21) and a '50 ohm microstrip W4 that matches the output impedance of Q203 to the input impedance of driver Q204.

The collector voltage of Q204 is coupled through R26 from the supply voltage, through collector stabilizing network L23 and R11 through collector feed network L22 and C15.

Collector current for Q204 is metered across tapped manganin resistor R26. The reading, taken in position "F" on the 10 Volt scale of the Test Set with the High Sensitivity button pressed, should be approximately 2.1 Amperes.

- WARNING -

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Be extremely careful to avoid damaging transistors when working with the PA assembly.

The output of Q204 is coupled through an impedance matching network (C209, C210, C36 and L24) and a 50 ohm microstrip, W5, to a power splitter consisting of microstrip transmission line W6-W9 and R12.

RF output power from Q204 (approximately 12 Watts) is split evenly between two identical class C power amplifiers Q205 and Q206 via their respective identical impedance matching networks. The impedance matching networks consist of C19, C211, C213, L27, L25 and C20, C212, C214, L26 and L28.

Collector voltage for Q205 and Q206 is supplied from the A+ line at C219-1 through identical collector stabilizing networks consisting of R13, L31, C23 and L32, R14 and C24 respectively.

Collector current for Q205 and Q206 is metered across tapped manganin resistor R27. The reading taken in position G on the 10 volt scale with the HIGH SENS button on the test set pressed. The meter reading should be 7.9 Amperes.

The output of Q205 and Q206 is coupled through identical impedance matching and RF power combining networks. The RF power combiner consists of micro strip transmission lines W12 and W13 and resistor 15. The combiner adds the outputs of Q205 and Q206 and applies the combined RF output to the low pass filter through 50 ohm micro strip W14. The RF power output is applied to antenna connector J202 through 50 ohm micro strip W1 in the low pass filter, to the antenna relay or to J202.

— CAUTION —

The placement of monolithic capacitors on the PA board is very critical; therefore, it is not recommended that the PA board be serviced in the field.

POWER CONTROL CIRCUIT

The Power Control Circuit, consists of CR1, U1, Q207 and the directional coupler (C30, C31, CR3, R16 and W15).

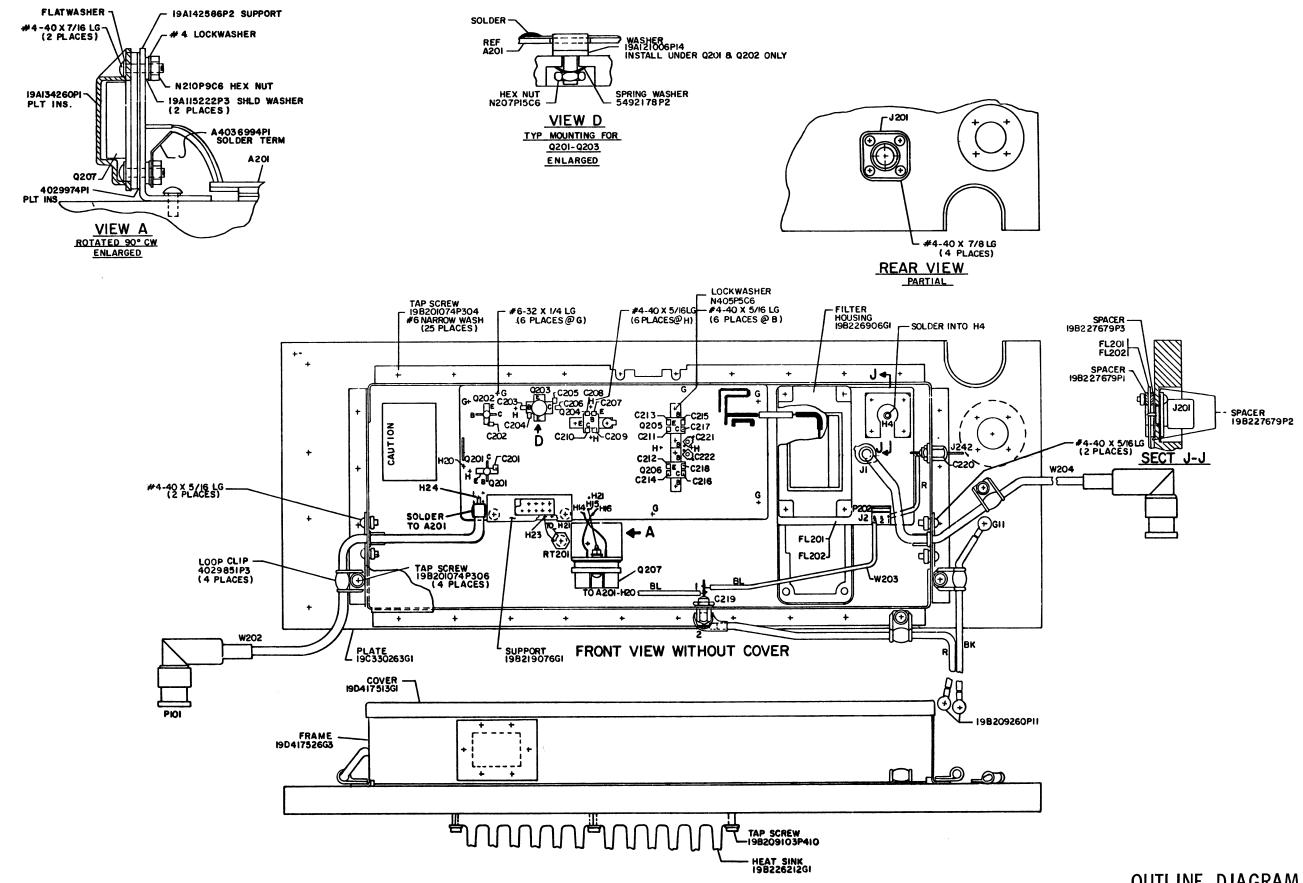
When the transmitter is keyed, rectified RF from CR1 is applied to a transistorized switch in the Power Control IC (U1), turning on the switch. The switch operates a voltage regulator. The directional coupler senses the forward power at the output of the power amplifier and feeds voltage back to the Power Control IC, resulting in feedback control of the voltage regulator output. A constant voltage is fed via pin 4 of U1 to Power Adjust potentiometer R24. The setting of R24 determines the voltage fed to the base and collector of Q201 and the collector of Q202. Reducing the supply voltage to these stages reduces the drive to the remaining stages of the power amplifier, thereby reducing the power output of the PA.

Overvoltage sensing of the supply voltage via pin 11 of U1 shuts down the driver when this condition occurs, thus protecting the driver and PA stages. The feedback power control performs the function of power leveling of the amplifier output over a range of varying input conditions such as drive level, DC voltage and load variations.

R29 is provided to limit the maximum power delivered to the antenna to prevent the probability of PA burn up due to misadjustment for excessive power. R29 is set to provide RF output 1 dB greater than rated power.

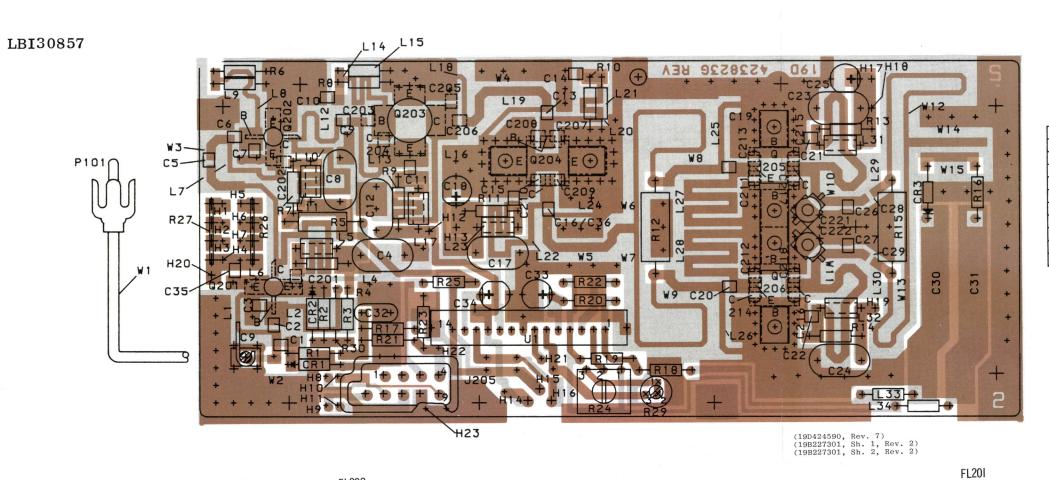
GENERAL ELECTRIC COMPANY• MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS•LYNCHBURG, VIRGINIA 24502 U.S.A.





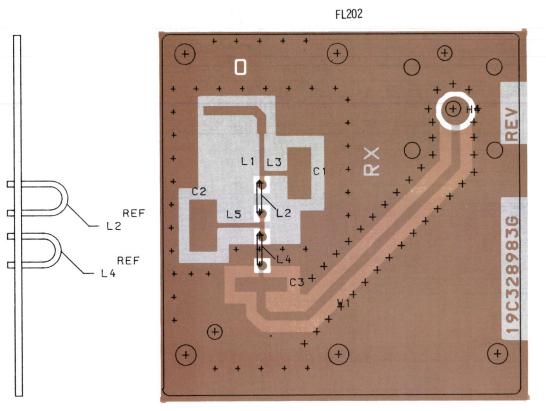
OUTLINE DIAGRAM

POWER AMPLIFIER 19D430488G1, G2

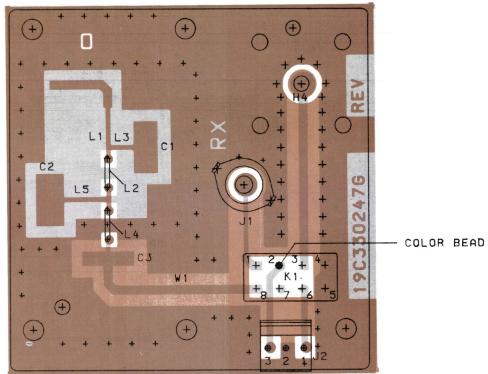


(19C328984, Rev. 0) (19A138346, Sh. 1, Rev. 0) (19A138346, Sh. 2, Rev. 0)

CONNECTIONS CHART						
FROM	TO	USING				
H1	H17	W18				
H2	H9	ST22-BR				
НЗ	H8	ST22-R				
H4	H12	W17				
H5	H13	W20				
H6	H10	ST22-6				
H7	H11	ST22-W				
H18	H19	W19				



REF L2 REF L4



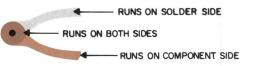
(19C330249, Rev. 0) (19A142581, Sh. 1, Rev. 0) (19A142581, Sh. 2, Rev. 0)

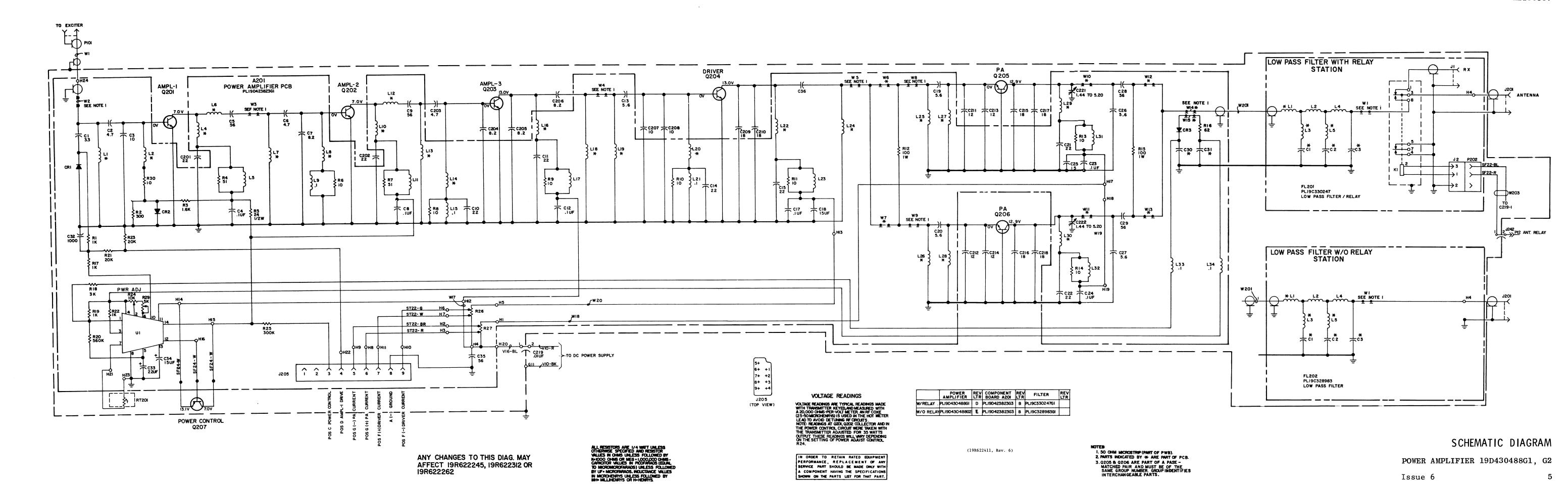
OUTLINE DIAGRAM

PA BOARD AND ASSEMBLIES

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Issue 4





LBI30857

PARTS LIST

						R26	19C850605P2
	TR	851-870 MHz, 35 WATT ANSMITTER POWER AMPLIPIER	J205	19B219374G1	Connector: 9 contacts.	and R27	190830603F2
	110	19D430488G1 W RELAY 19D430488G2 W/O RELAY				R29	19A700016P3
		ISSUE 7	ļ ,,			R30	19A700106P15
	1		L1 and L2		(Part of 19D423824P1 printed board).		
SYMBOL	GE PART NO.	DESCRIPTION	L4		(Part of 19D423824Pl printed board).	,	1004203004
			L5	19A701091G1	Coil.	U1	19D429709G4
A201		POWER AMPLIFIER BOARD	L6		(Part of 19D423824P1 printed board).		
AZOI		19D423823G3	thru L8	1		W2 thru	
			L9	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res	W15	
Cl	19A134419P1	Ceramic: 3.3 pF + or25 pF, 50 VDCW, temp			max; sim to Jeffers 4416-1K.	W17	19B227659P4
		coef 0 + or -120 PPM.	L10 L11	19A701091G1	(Part of 19D423824P1 printed board).	W18	19B227659P2
C2	19A134419P5	Ceramic: 4.7 pF + or25 pF, 50 VDCW, temp coef 0 + or -60 PPM.	L12	19A/01091G1	Coil. (Part of 19D423824Pl printed board).	W19	19B227659P1
С3	19A134419P13	Ceramic: 10 pF + or -5%, 50 VDCW, temp coef 0 +	thru L14		(rait of 195423824F1 printed board).	W20	19B227659P3
		or -60 PPM.	L15	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res		
C4	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.			max; sim to Jeffers 4416-1K.	C201	19A134419P21
C5	19A134419P31	Ceramic: 56 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM.	L16		(Part of 19D423824Pl printed board).	and C202	
C6	19A134419P5	Ceramic: 4.7 pF + or25 pF, 50 VDCW, temp	L17	19A701091G1	Coil.	C203	19A134419P5
С7	19A134419P11	coef 0 + or -60 PPM. Ceramic: 8.2 pF + or -5%, 50 VDCW, temp coef 0	L18 thru	1	(Part of 19D423824P1 printed board).	C204	19A134419P11
C/	198134419711	+ or -60 PPM.	L20			thru C206	158134415111
C8	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.	L21	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.	C207	19A134419P13
С9	19A134419P31	Ceramic: 56 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM.	L22		(Part of 19D423824Pl printed board).	and C208	
C10	19A134419P21	Ceramic: 22 pF + or -5%, 50 VDCW, temp coef 0 +	L23	19A701091G1	Coil.	C209	19A134418P19
and Cll		or -30 PPM.	L24 thru		(Part of 19D423824Pl printed board).	and C210	1
C12	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.	L30			C211	19A134419P15
C13	19A134419P7	Ceramic: 5.6 pF + or -5%, 50 VDCW, temp coef 0	L31 and	19A701091G1	Coil.	thru C214	1
a) 4	10013441000	+ or -60 PPM.	L32			C215	19A134418P19
Cl4 and	19A134419P21	Ceramic: 22 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM.	L33 and	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.	thru C218	
C15 C17	19A116080P107	Polyoptor, 0.1 up + or -10% 50 VDCW	L34			C219 and	19A116708P1
C17	19A134202P8	Polyester: 0.1 uF + or -10%, 50 VDCW. Tantalum: 15 uF + or -20%, 20 VDCW.				C220	
C19	19A134419P7	Ceramic: 5.6 pF + or -5%, 50 VDCW, temp coef 0	Rl	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	C221 and	19A703518P2
and C20		+ or -60 PPM.	R2	3R152P301J	Composition: 300 ohms + or -5%, 1/4 w.	C222	
C21	19A134418P21	Ceramic: 22 pF + or -5%, 50 VDCW, temp coef 0 +	R3	3R152P162J	Composition: 1.6K ohms + or -5%, 1/4 w.		
and C22		or -30 PPM.	R4	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.	FL201	
C23	19A116080P107	Polyester: 0.1 uF + or -10%, 50 VDCW.	R5	3R77P240J	Composition: 24 ohms + or - 5%, 1/2 w.	11	
and C24			R6	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	, ,	19A700049P2
C25	19A134202P8	Tantalum: 15 uF + or -20%, 20 VDCW.	R7	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.	J1	194700049F2
C26	19A134418P7	Ceramic: 5.6 pF + or -5%, 50 VDCW, temp coef 0	R8 thru	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	J2	19A116659P55
and C27		+ or -60 PPM.	R11		50.14		
C28 and	19A134418P31	Ceramic: 56 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM.	R12	19A700112P39	Composition: 100 ohms + or - 5%, 1 w.	1 1	İ
C29		01 33 11	R13 and R14	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	K1	19A700061P1
C30 and		(Part of 19D423824Gl printed board).	R15	19A700112P39	Composition: 100 ohms + or - 5%, 1 w.		
C31			R16	3R152P620J	Composition: 62 ohms + or -5%, 1/4 w.	1	1
C32	19A116655P19	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.	R17	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	L2	19A136863P1
C33	19A134202P6	Tantalum: 22 uF + or -20%, 15 VDCW.	R18	3R152P302J	Composition: 3K ohms + or - 5%, 1/4 w.	L4	19A136863P1
C34	19A134202P8	Tantalum: 15 uF + or -20%, 20 VDCW.	R19	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	FL202	19C328983G1
C35	19A134419P31	Ceramic: 56 pF + or -5%, 50 VDCW, temp coef 0 +	R20	3R152P564J	Composition: 560K ohms + or -5%, 1/4 w.	1 1202	19032098301
C36	19A134418P9	or -30 PPM.	R21	3R152P203J	Composition: 20K ohms + or - 5%, 1/4 w.		
C30	17813441019	Ceramic: 6.8 pF + or -5%, 50 VDCW, temp coef 0 + or -60 PPM.	R22	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	J201	7777145P5
			R23	3R152P203J	Composition: 20K ohms + or - 5%, 1/4 w.		
CR1	19A116052P1	Silicon, hot carrier: Fwd drop .350 volts max.	R24	19A116559P106	Variable cermet: 10K ohms + or - 20%, 1/2 w; sim to CTS Series 360.	P101	
CR2	19A115775P1	Silicon, fast recovery, 225 mA, 50 PIV.	R25	3R152P304J	Composition: 300K ohms + or -5%, 1/4 w.		
CR3	19A116052P2	Silicon, fast recovery; sim to Hewlett Packard	KZ5	3813213040	Composition: Con Olano . Or Jo, 1/4 w.	Q201	19A134430P1
		5082-2811.					
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			1 L] [

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	1			R26	19C850605P2	Shunt resistor.	Q202	19A134430P2	Silicon, NPN.
	J205	19B219374G1	Connector: 9 contacts.	and R27			Q203	19A134431P1	Silicon, NPN.
				R29	19A700016P3	Variable, cermet: 4.7K ohms + or -10%, 1/2 w.	Q204	19A134432P1	Silicon, NPN.
	Lı		(Part of 19D423824P1 printed board).	R30	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	Q205 and		(Part of 19A144342G1 Transistor Kit).
7	and L2		(,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,				Q206		C/1/ DVD
	L4		(Part of 19D423824P1 printed board).	Ul	19D429709G4	Power control, low current out.	Q207	19A116758P1	Silicon, PNP.
┫.	L5	19 A 701091G1	Coil.	01	19042970904	rower control, low current out.	1		
	L6		(Part of 19D423824P1 printed board).				RT201	19A129379G1	Thermistor: 40K ohms + or - 20%, color code white; sim to Carborundum Type M0806J-5.
	thru L8			W2 thru		(Part of 19D423824P1 printed board).			white, sim to carboraldam Type hoses st
	L9	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res	W15					
			max; sim to Jeffers 4416-1K.	W17	19B227659P4	Jumper.	W201	19A136859G1	Cable, RF.
1	L10	10170100101	(Part of 19D423824P1 printed board).	W18	19B227659P2	Jumper.	W202	19B227683G3	Cable: approx 3 feet long.
	Lll	19A701091G1	Coil.	W19	19B227659P1	Jumper.	W203	19A142600G1	Cable.
	L12 thru		(Part of 19D423824P1 printed board).	W20	19B227659P3	Jumper.	W204	19A142607G1	Cable: approx 2 feet long.
	L14 L15	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res						MISCELLANEOUS
	""	1382034201101	max; sim to Jeffers 4416-1K.	C201	19A134419P21	Ceramic: 22 pF + or -5%, 50 VDCW, temp coef 0 +		19D417513G1	PA Cover. (Used in Group 1).
	L16		(Part of 19D423824P1 printed board).	and C202		or -30 PPM.		19B233315G1	Filter Web. (W RELAY).
	L17	19 A 701091G1	Coil.	C203	19A134419P5	Ceramic: 4.7 pF + or25 pF, 50 VDCW, temp		19B233315G2	Filter Web. (W/O RELAY).
	L18 thru		(Part of 19D423824P1 printed board).	220.4	19A134419P11	coef 0 + or -60 PPM.		N80P13016B6	Machine screw: #6(.138)-32 x 1.0. (Secures filter
	L20			C204 thru	194134419711	Ceramic: 8.2 pF + or -5%, 50 VDCW, temp coef 0 + or -60 PPM.	1	10041607503	casting).
	L21	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.	C206 C207	19A134419P13	Ceramic: 10 pF + or -5%, 50 VDCW, temp coef 0 +		19D416275P3	Filter casting. Spacer. (Used with FL201 & FL202).
	L22		(Part of 19D423824P1 printed board).	and C208	194134419713	or -60 PPM.		19B227679P2 19B201074P312	Tap screw, Phillips POZIDRIV: No. 6-32 x 3/4.
	L23	19 A 701091G1	Coil.	C208	19A134418P19	Ceramic: 18 pF + or -5%, 50 VDCW, temp coef 0 +		1982010742312	(Secures support to A201).
	L24		(Part of 19D423824Pl printed board).	and C210	198154410119	or -30 PPM.		19B219076G1	Support. (Used with A201).
	thru L30			C211	19A134419P15	Ceramic: 12 pF + or -5%, 50 VDCW, temp coef 0 +		19B226212G1	Heat sink.
	L31	19A701091G1	Coil.	thru C214		or -30 PPM.		19B209103P410	Tap screw, hex head: No. 8-32 x 5/8. (Secures Heat Sink).
	and L32			C215	19A134418P19	Ceramic: 18 pF + or -5%, 50 VDCW, temp coef 0 +		19A121006P14	Washer. (Used with Q201 & Q202).
-	L33	19B209420P101	Coil, RF: .10 uH + or - 10%, 0.8 ohms DC res max; sim to Jeffers 4416-1K.	thru C218		or -30 PPM.		5492178P2	Washer, spring tension: sim to Wallace Barnes
	and L34		max, Sim to Serrers 4410 IN.	C219	19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20			375-20. (Used with Q201 & Q202).
				and C220		amps; sim to Erie 327050X5W0103P.		19A702782P5	Nut, hex, brass: No. 8-32. (Used with Q201 & Q202).
	Rl	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	C221	19A703518P2	Variable: 1.44 to 5.20 pF, 125 VDCW; sim to EF		7878455Pl	Lug terminal; sim to GE89473. (Used with Q204).
	R2	3R152P301J	Composition: 300 ohms + or -5%, 1/4 w.	and C222		Johnson 186-0607-175.		N405P5B6	Lockwasher, spring: #4. (Used with Q204).
	R3	3R152P162J	Composition: 1.6K ohms + or -5%, 1/4 w.					7139898P3	Nut, hex, brass: No. 1/4-28. (Used with C219).
	R4	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.	FL201		800 MHz FILTER/RELAY ASSEMBLY		NP280071	Nameplate. (CAUTION).
1	R5	3R77P240J	Composition: 24 ohms + or - 5%, 1/2 w.			19C330247G1		19A701863P13	Cable clip. (Used with W202).
l	R6	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.					19B201074P306	Tap screw, Phillips POZIDRIV: No. 6-32 x 3/8. (Used with cable clip).
	R7	19A700106P32	Composition: 51 ohms + or - 5%, 1/4 w.	J1	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058.		19B209268P113	Terminal, solderless: sim to AMP 2-34835-4.
l	R8	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	J2	19A116659P55	Connector, printed wiring: 3 contacts rated at		1382032001113	(Used with red cable).
	thru Rll					5 amps; sim to Molex 09-65-1031.		19B209260P11	Solderless terminal. (Used with red & black cable).
	R12	19A700112P39	Composition: 100 ohms + or - 5%, 1 w.					19A700136P7	Sleeving, insulative. (Used with red cable).
İ	R13 and	19A700106P15	Composition: 10 ohms + or - 5%, 1/4 w.	K1	19A700061P1	Hermetic sealed: 180 to 341 ohms coil res,		19B227679P1	Spacer. (Used with FL201 & FL202).
1	R14					8-16.3 VDC; sim to GE 3SAV1760A2, CP Clare HPW-1201558, or Potter-Brumfield HCM6160.		19A134260P1	Insulator cover. (Used with Q207).
	R15	19A700112P39	Composition: 100 ohms + or - 5%, 1 w.					4029974P1	Insulator, plate: aluminum. (Used with Q207).
	R16	3R152P62OJ	Composition: 62 ohms + or -5%, 1/4 w.	1	10113606371			4036994P1	Terminal, solderless. (Used with Q207).
	R17	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	L2	19A136863P1	Coil.		19A115222P3	Washer, shield. (Secures Q207).
1	R18	3R152P302J	Composition: 3K ohms + or - 5%, 1/4 w.	L4	19A136863P1	Coil.		N210P9B6	Nut, hex: #4 (.112) - 40. (Secures Q207).
	R19	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	FL202	19C328983G1	Lowpass filter.		19D438235G1	PA Cover, Includes fan. (Used in Group 2).
	R20	3R152P564J	Composition: 560K ohms + or -5%, 1/4 w.						
	R21	3R152P203J	Composition: 20K ohms + or - 5%, 1/4 w.	J201	7777145P5	Receptacle: sim to Amphenol 82-97.			
	R22	19A700106P63	Composition: 1K ohms + or - 5%, 1/4 w.	0201	,,,,14313	ASSECTION OF THE CO. WINDSHIP OF THE CO. T. C.			
.	R23	3R152P203J	Composition: 20K ohms + or - 5%, 1/4 w.				1		
	R24	19A116559P106	Variable cermet: 10K ohms + or - 20%, 1/2 w; sim to CTS Series 360.	P101		(Part of W201).			
	R25	3R152P304J	Composition: 300K ohms + or -5%, 1/4 w.						
]	1		Q201	19A134430P1	Silicon, NPN.			
			1	1					

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A 19D430488G1 & G2 800 Mhz Power Amplifier Assembly

 To improve reliability. Changed Q207 from 19A116375P1 to 19A116758P1.
- REV. A 19D423823G3 800 MHz Power Amplifier Board

 To reduce the probablity of P.A. Burnout due to misadjustment for excessive power. Added R29.
- REV. B 19D423823G3 800 MHz POWER AMPLIFIER BOARD

To improve input VSWR. Replaced L3 with R30.

- L3 was: 19B209420P101 RF Coil: .01 uH ±10%.
- REV. C Not used.
- REV. D 19D430488G1, 2, Power Amplifier
 To add tuning adjustment Added C221 & C222.
- REV. E <u>19D430488G2 Power Amplifier</u>
 To prevent PA from overheating. Changed
 PA cover to a new one containing a fan.
 The old one was: 19D417513G1.